



# WBA0115A

## 0.10 – 1.4 GHz LOW NOISE WIDE BAND AMPLIFIER

REV A  
April 2011

### Key Features



- 0.10 ~ 1.4 GHz
- 35.0 dBm output IP<sub>3</sub>
- 17.0 dBm Output P<sub>1dB</sub>
- 20.0 dB Gain
- 0.70 dB Noise Figure
- 1.35:1 VSWR
- Single power supply
- >34 years MTBF
- Unconditional stable
- RoHS compliant
- Meet MIL-STD-202

### Product Description

WBA0115A integrates WanTcom proprietary power amplifier technology, high frequency micro electronic assembly techniques, and high reliability design to realize optimum low noise figure, wideband, high linearity, and unconditional stable performances together. With single +12.0V DC operation, the amplifier has optimal input and output matching in the specified frequency range at 50-Ohm impedance system. The amplifier has standard SMA connectorized WP-11 gold plated housing.

### Applications

- Mobile Infrastructures
- Cellular
- Paging System
- Measurement
- Fixed Wireless

### Specifications

Summary of the electrical specifications WBA0115A at room temperature

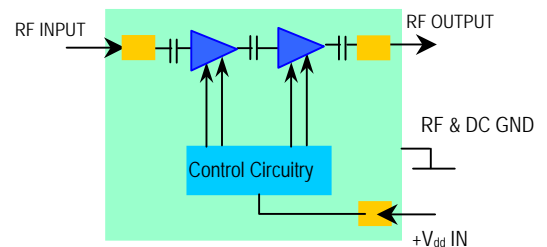
Index	Testing Item	Symbol	Test Constraints	Min	Nom	Max	Unit
1	Gain	S <sub>21</sub>	0.10 – 1.4 GHz	16	20	24	dB
2	Gain Variation	ΔG	0.10 – 1.4 GHz		+/- 1.5	+/-2.0	dB
3	Input VSWR	SWR <sub>1</sub>	0.10 – 1.4 GHz		1.35:1	1.5:1	Ratio
4	Output VSWR	SWR <sub>2</sub>	0.10 – 1.4 GHz		1.35:1	1.5:1	Ratio
5	Noise Figure	NF	0.10 – 1.4 GHz		0.70	0.9	dB
6	Reverse Isolation	S <sub>12</sub>	0.10 – 1.4 GHz	20	22		dB
7	Output IP <sub>3</sub>	IP <sub>3</sub>	0.10 – 1.4 GHz	33	35		dBm
8	Output Power 1dB compression Point	P <sub>1dB</sub>	0.10 – 1.4 GHz	16	17		dBm
9	Current Consumption	I <sub>dd</sub>	V <sub>dd</sub> = +12 V		60		mA
10	Power Supply Voltage	V <sub>dd</sub>		+7	+12	+15	V
11	Operating Temperature	T <sub>o</sub>		-40		+85	°C
12	Maximum Average RF Input Power	P <sub>IN,MAX</sub>	DC – 6 GHz			10	dBm

### Absolute Maximum Ratings

Parameters	Units	Ratings
DC Power Supply Voltage	V	15
Drain Current	mA	75
Total Power Dissipation	W	1.0
RF Input Power	dBm	10
Channel Temperature	°C	150
Storage Temperature	°C	-55 ~ 125
Operating Temperature	°C	-40 ~ 85
Thermal Resistance	°C/W	75

Operation of this device above any one of these parameters may cause permanent damage.

### Functional Block Diagram



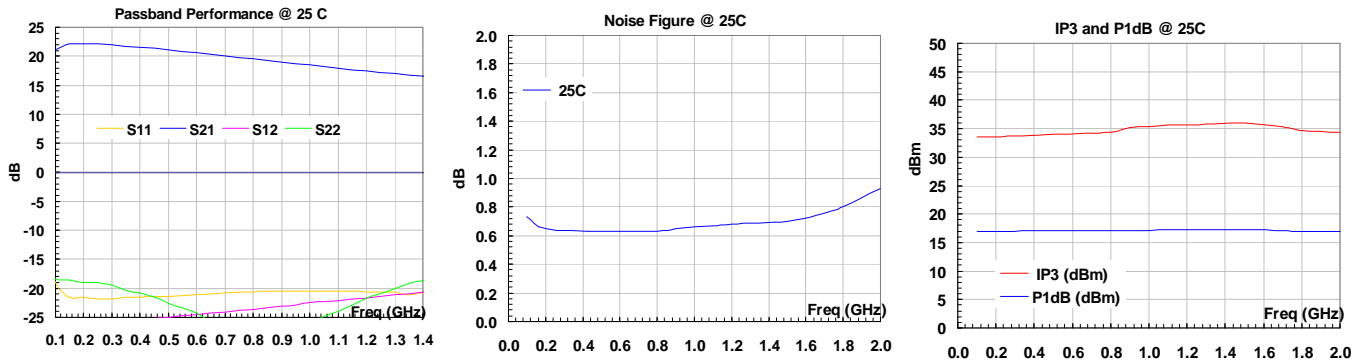
### Ordering Information

Model Number	WBA0115A
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Specifications and information are subject to change without notice.



### Typical Data:



### Outline, WP-11 Housing

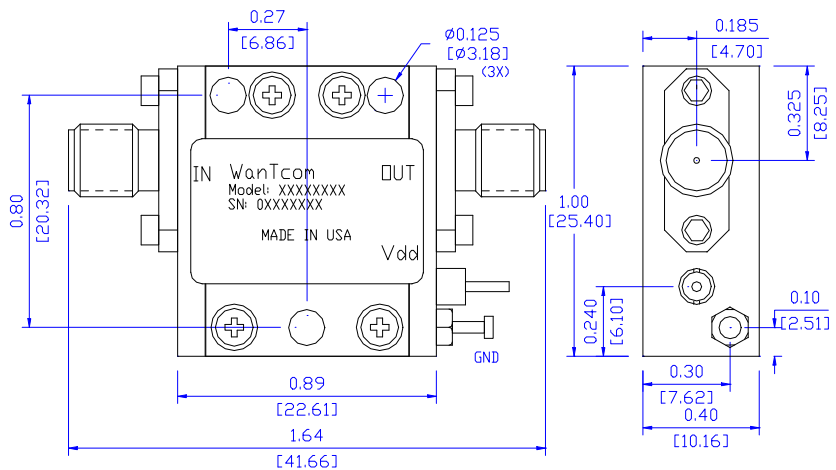
UNITS: INCH  
[mm]

BODY: Brass

Finish: Gold Plating

RF Connector: SMA F Gold Field Replaceable

V<sub>dd</sub> PWR: Feed through



### Application Notes:

#### A. SMA Torque Wrench Selection

Always use a torque wrench with 5 ~ 6 inch-lb coupling torque setting for mating the SMA cables to the amplifier. Never use torque more than 8 inch-lb wrench for tightening the mating cable to the connector. Otherwise, the permanent damage will occur to the SMA connectors of the amplifier. 8710-1582 (5 inch-lb) is one of the ideal torque wrench choice from Agilent Technology.

#### B. DC Power Line Connection

Strip the insulation layer at the end of DC power supply wire. The stripped distance should be in the range of 0.100" to 0.200". The 24 ~ 26 American Wire Gauge wire is suitable. Wound the stripped terminal wire about 1 to 2 turns on the DC feed thru center pin. Solder the wounded wire and the center pin together. Clean the soldering area by Q-tip with alcohol to remove the flux and residue.

Repeat the process to solder the DC return wire on the ground turret.

#### C. Mounting the Amplifier

Use three pieces of #4-40 with longer than 9/16" screws for mounting the amplifier on a metal-based chase. Flat and spring washers are needed to prevent the screw loosening during the shock and vibration. Always use the appropriate torque setting of the power screwdriver to mount them.

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